# **PC904**

## **Built-in Voltage Detection Circuit Type Photocoupler**

\*\* Lead forming type (I type) and taping reel type (P type) are also available. (PC904I/PC904P)

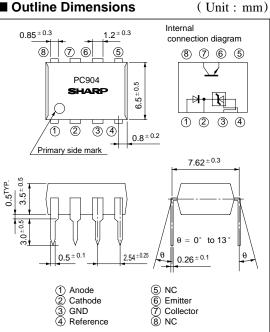
#### ■ Features

- 1. Built-in voltage detection circuit
- 2. High isolation voltage between input and output ( $V_{iso}$ : 5 000 $V_{rms}$ )
- 3. Standard 8-pin dual-in-line package
- 4. Recognizerd by UL, file No. E64380

### ■ Applications

1. Switching power supplies

### **■** Outline Dimensions



## ■ Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$ 

	Parameter	Symbol	Rating	Unit
	Anode current	$I_A$	50	mA
	Anode voltage	V <sub>A</sub>	30	V
Input	Reference input current	IREF	10	mA
	Power dissipation	P	250	mW
	Collector-emitter voltage	V <sub>CEO</sub>	35	V
	Emitter-collector voltage	V ECO	6	V
Output	Collector current	Ic	50	mA
	Collector power dissipation	P <sub>C</sub>	150	mW
	Total power dissipation	P tot	350	mW
*1 Isolation voltage		V iso	5 000	V <sub>rms</sub>
Operating temperature		T opr	- 25 to + 85	°C
	Storage temperature	T stg	- 40 to + 125	°C
	*2Soldering temperature	T sol	260	°C

<sup>\*1 40</sup> to 60% RH AC for 1 minute

<sup>\*2</sup> For 10 seconds

## **■** Electro-optical Characteristics

 $(Ta=25^{\circ}C)$ 

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit	Fig.
Input	Reference voltage	V REF	$V_K = V_{REF}$ , $I_A = 10mA$	2.40	2.495	2.60	V	1
	*3Temperature change in reference voltage	V <sub>REF(dev)</sub>	$V_K = V_{REF}$ , $I_A = 10mA$ , $Ta = -25 \text{ to} + 85^{\circ}C$	-	8	40	mV	1
	Voltage variation ratio in reference voltage	$\Delta V_{REF}/\Delta V_{A}$	$I_A = 10mA, \ \Delta V_A = 30V - V_{REF}$	-	- 1.4	- 5	mV/V	2
	Reference input current	IREF	$I_A = 10 \text{mA}$ , $R_3 = 10 \text{k}\Omega$	-	2	10	μΑ	3
	*4Temperature change in reference input current	$I_{REF(dev)}$	$I_A = 10 \text{mA}, R_3 = 10 \text{k} \Omega, Ta = -25 \text{ to} + 85^{\circ}\text{C}$	-	0.4	3	μΑ	3
	Minimum drive current	$I_{MIN}$	$V_K = V_{\text{REF}}$	-	1	2	mA	1
	OFF-state anode current	$I_{OFF}$	$V_A = 30V, V_{REF} = GND$	-	0.1	2	μΑ	4
	Anode-cathode forward voltage	$V_F$	$V_K = V_{REF}$ , $I_A = 10mA$	-	1.2	1.4	V	1
Output	Collector dark current	$I_{CEO}$	$V_{CE} = 35V$	-	1 x 10 -9	1 x 10 -7	A	5
Transfer charac- teristics	*5Current transfer ratio	CTR	$V_K = V_{REF}$ , $I_A = 5mA$ , $V_{CE} = 5V$	50	-	600	%	6
	Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$V_K = V_{REF}$ , $I_A = 10mA$ , $I_C = 1mA$	-	0.1	0.2	V	6
	Isolation resistance	R <sub>ISO</sub>	40 to 60% RH, DC500V	5 x 10 <sup>10</sup>	1 x 10 <sup>11</sup>	-	Ω	-
	Floating capacitance	$C_{\mathrm{f}}$	V = 0, $f = 1kHz$	-	0.6	1.0	pF	-

<sup>\*3</sup> V  $_{REF(dev)} = V_{REF(MAX.)} - V_{REF(MIN.)}$ 

Classification table of current transfer ratio is shown below.(4 models)

Model No.	Rank mark	CTR (%)		
PC904A	A	50 to 150		
PC904B	В	100 to 300		
PC904C	С	250 to 600		
PC904	A, B or C	50 to 600		

### **■** Test Circuit

Fig. 1

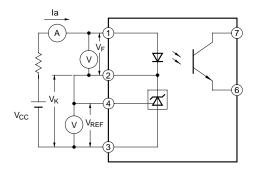
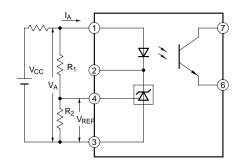


Fig. 2



<sup>\*4</sup> I  $_{REF(dev)}\!=I_{REF(MAX.)}$  -  $I_{REF(MIN.)}$ 

<sup>\*5</sup> CTR = I  $_{\rm C}$  / I  $_{\rm A}$  x 100 (%)

Fig. 3

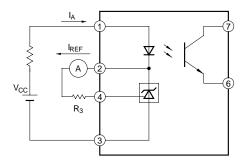


Fig. 4

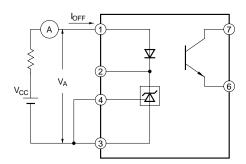


Fig. 5

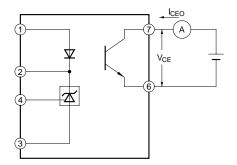


Fig. 6

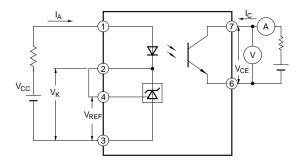


Fig. 7 Anode Current vs. Ambient

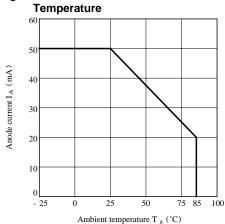


Fig. 8 Input Power Dissipation vs.
Ambient Temperature

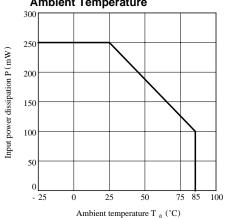


Fig. 9 Collector Power Dissipation vs.
Ambient Temperature

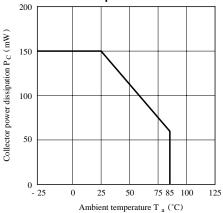


Fig.11 Relative Current Transfer Ratio vs.
Ambient Temperature

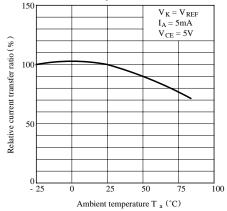


Fig.13-a Anode Current vs. Reference Voltage

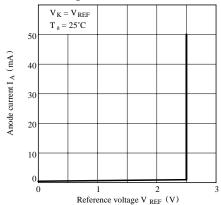


Fig.10 Power Dissipation vs. Ambient Temperature

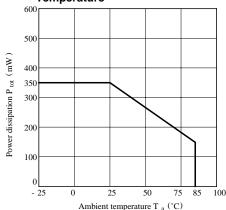


Fig.12 Collector Dark Current vs.
Ambient Temperature

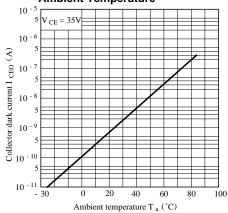


Fig.13-b Anode Current vs. Reference Voltage

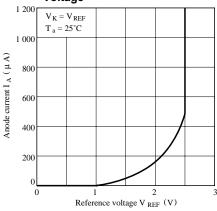


Fig.14 OFF-state Anode Current vs. Ambient Temperature

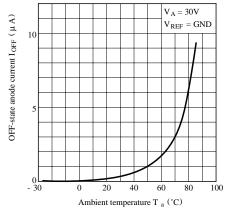


Fig.16 Reference Input Current vs.
Ambient Temperature

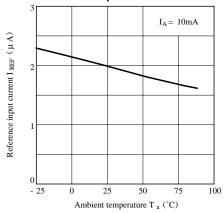


Fig.18-a Voltage Gain (1) vs. Frequency

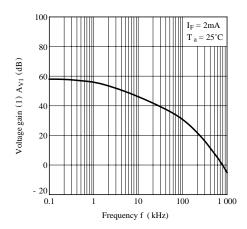


Fig.15 Reference Voltage vs. Ambient Temperature

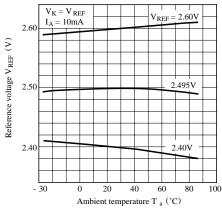
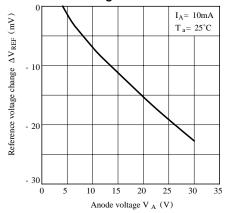
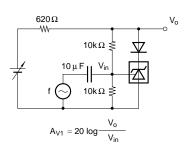


Fig.17 Reference Voltage Change vs. Anode Voltage



Test Circuit for Voltage Gain (1) vs. Frequency



### Fig.18-b Voltage Gain (2) vs. Frequency

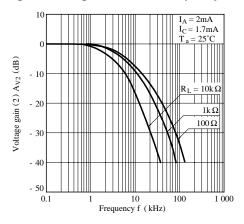


Fig.19 Anode Current vs. Load Capacitance

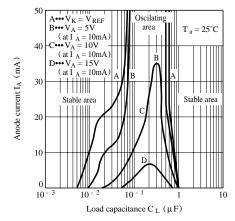
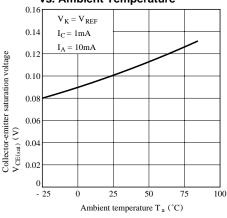
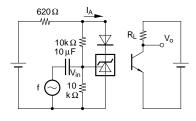


Fig.20 Collector-emitter Saturation Voltage vs. Ambient Temperature



# Test Circuit for Voltage Gain (2) vs. Frequency



# Test Circuit for Anode Current vs. Load Capacitance

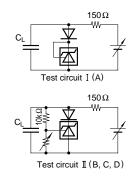
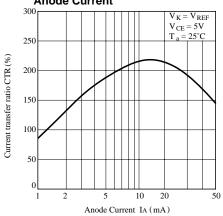


Fig.21 Current Transfer Ratio vs.
Anode Current



#### ■ Precautions for Use

Handle this product the same as with other integrated circuits against static electricity.

• As for other general cautions, refer to the chapter "Precautions for Use"

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